

**TOSHIBA****1SS402**

TENTATIVE

TOSHIBA DIODE SILICON EPITAXIAL SCHOTTKY BARRIER TYPE

**1SS402**

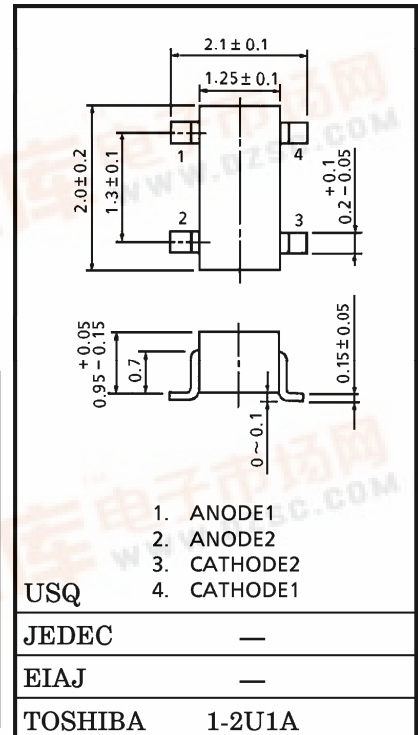
HIGH SPEED SWITCHING APPLICATIONS

Unit in mm

- Two independent diodes are mounted on four-pin ultra-small packages that are suitable for higher mounting densities.
- Low Forward Voltage :  $V_F(3) = 0.50\text{ V (Typ.)}$
- Low Reverse Current :  $I_R = 0.5\text{ }\mu\text{A (Max.)}$
- Small Total Capacitance :  $C_T = 3.9\text{ pF (Typ.)}$

MAXIMUM RATINGS ( $T_a = 25^\circ\text{C}$ )

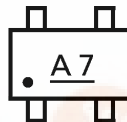
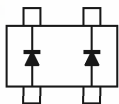
CHARACTERISTIC	SYMBOL	RATING	UNIT
Maximum (Peak) Reverse Voltage	$V_{RM}$	25	V
Reverse Voltage	$V_R$	20	V
Maximum (Peak) Forward Current	$I_{FM}$	100 (*)	mA
Average Forward Current	$I_O$	50 (*)	mA
Surge Current (10ms)	$I_{FSM}$	1 (*)	A
Power Dissipation	P	100	mW
Junction Temperature	$T_j$	125	$^\circ\text{C}$
Storage Temperature Range	$T_{stg}$	$-55\sim 125$	$^\circ\text{C}$

(\*) Unit Rating. Total Rating = Unit Rating  $\times$  1.5ELECTRICAL CHARACTERISTICS ( $T_a = 25^\circ\text{C}$ )

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Forward Voltage	$V_F(1)$	$I_F = 1\text{ mA}$	—	0.33	—	V
	$V_F(2)$	$I_F = 5\text{ mA}$	—	0.38	—	
	$V_F(3)$	$I_F = 50\text{ mA}$	—	0.50	0.55	
Reverse Current	$I_R(1)$	$V_R = 20\text{ V}$	—	—	0.5	$\mu\text{A}$
Total Capacitance	$C_T$	$V_R = 0, f = 1\text{ MHz}$	—	3.9	5.0	pF

PIN ASSIGNMENT (TOP VIEW)

MARKING



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